

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	700674	CMOS neaer4 resistor\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 13:22
L2	1827	CMOS near4 resistor\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 17:13
L3	576	2 and contact\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 13:22
L4	78	3 and ohmic	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 16:44
L5	77543	resistor.clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 13:24
L6	11070	5 and (CMOS or (metal adj oxide adj semiconductor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 13:25
L7	1532	6 and ((CMOS or (metal adj oxide adj semiconductor)) near8 resistor\$1)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 13:28
L8	502	7 and (contact\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 13:28
L9	74	8 and ohmic	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 17:13

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L10	2	("6124179").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 13:49
L11	74	9 and (resistor\$1.clm. or (ohmic adj contact\$3).clm.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 17:12
L12	55	11 and contact\$3.clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 13:52
L13	48	12 and CMOS	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 13:52
L14	48	13 and (\$3type or \$3well)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 13:52
L15	390	resistor.clm. and CMOS.clm.	US-PGPUB	OR	OFF	2006/05/23 13:53
L16	43	15 and (high adj resistance\$1)	US-PGPUB	OR	OFF	2006/05/23 13:53
L17	5	16 and silicon.clm.	US-PGPUB	OR	OFF	2006/05/23 17:01
L18	2	("6124179").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 16:45
L19	2	("6300668").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 16:45
L20	16	((("6992346") or ("6340835") or ("6340834") or ("5825074") or ("5545584") or ("5302549") or ("4332070"))).PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 17:48
L21	2	("6300668").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 17:04

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L22	2	9 and BPSG	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 17:11
L23	2	11 and BPSG	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 17:12
L24	0	10 and BPSG	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 17:13
L25	1	10 and (passivation adj3 layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 17:14
L26	278	resistor.clm. and passivation.clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 17:48
L27	3	2 and 26	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 17:49
L28	84	26 and ((metal near3 contact\$3) or (metal near4 plug\$1))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 17:50
L29	813046	28 contact\$3.clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 17:50
L30	69	28 and contact\$3.clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 17:50
L31	13	30 and cmos	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/23 17:51